Nouman Zia

List of Publications by Year in descending order

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		1684188	1588992	
12	92	5	8	
papers	citations	h-index	g-index	
12	12	12	68	
all docs	docs citations	times ranked	citing authors	

#	Article	IF	CITATIONS
1	High power (60 mW) GaSb-based 1.9 <i>μ < /i> m superluminescent diode with cavity suppression element. Applied Physics Letters, 2016, 109, .</i>	3.3	21
2	GaSb diode lasers tunable around 2.6 $\langle i \rangle \hat{l} / 4 \langle i \rangle \langle b \rangle$m using silicon photonics resonators or external diffractive gratings. Applied Physics Letters, 2020, 116, .	3.3	21
3	GaSb superluminescent diodes with broadband emission at 2.55 <i>μ</i> m. Applied Physics Letters, 2018, 112, .	3.3	15
4	Hybrid silicon photonics DBR laser based on flip-chip integration of GaSb amplifiers and Âμm-scale SOI waveguides. Optics Express, 2022, 30, 24995.	3.4	11
5	High-power single mode GaSb-based 2 <i>μ</i> m superluminescent diode with double-pass gain. Applied Physics Letters, 2019, 115, .	3.3	7
6	Multi-wavelength mid-IR light source for gas sensing. Proceedings of SPIE, 2017, , .	0.8	6
7	High power GalnNAs superluminescent diodes emitting over 400 mW in the $1.2 < i > \hat{l} \frac{1}{4} < i> m$ wavelength range. Applied Physics Letters, 2019, 115, .	3.3	5
8	Integrated multi-wavelength mid-IR light source for gas sensing. , 2018, , .		4
9	Precise length definition of active GaAs-based optoelectronic devices for low-loss silicon photonics integration. Optics Letters, 2020, 45, 943.	3.3	2
10	Design Strategies for Power Scaling of GaSb-Based Superluminescent Diodes for 2 – 3 Î⅓m Wavelength Range. , 2019, , .		0
11	GaSb-Based 2.55 \hat{l} 4m External Cavity Diode Lasers Employing Ruled Diffraction Gratings and External Silicon Photonics Vernier Reflectors. , 2019, , .		0
12	Development of GaSb superluminescent LEDs for programmable light source for gas sensing. , 2017, , .		0